

FAIRCHILD

A Schlumberger Company

BAY74

High Conductance
Ultra Fast Diode

T-03-09

- t_{rr} ...4.0 ns (MAX)
- C...3.0 pF (MAX)

PACKAGE
BAY74 DO-35

ABSOLUTE MAXIMUM RATINGS (Note 1)

Temperatures
 Storage Temperature Range -65° C to +200° C
 Maximum Operating Junction Temperature +175° C
 Lead Temperature +280° C

Power Dissipation (Note 2)
 Maximum Total Dissipation at 25° C Ambient 500 mW
 Linear Deviation Factor (from 25° C) 3.33 mW

Maximum Voltage and Currents

WIV	Working Inverse Voltage	35 V
IO	Average Rectified Current	100 mA
IF	Continuous Forward Current	300 mA
IF	Recurent Peak Forward Current	400 mA
IF (surge)	Peak Forward Surge Current	1.0 A
	Pulse Width = 1.0 s	4.0 A
	Pulse Width = 1.0 μs	

ELECTRICAL CHARACTERISTICS (25° C Ambient Temperature unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	MAX	UNITS	TEST CONDITIONS
VF	Forward Voltage	0.85	1.10	V	IF = 300 mA
		0.82	1.00	V	IF = 200 mA
		0.78	0.93	V	IF = 100 mA
		0.73	0.88	V	IF = 50 mA
		0.65	0.77	V	IF = 10 mA
		0.54	0.65	V	IF = 1.0 mA
IR	Reverse Current		100	nA	VR = 35 V
			100	μA	VR = 35 V, TA = 125° C
BV	Breakdown Voltage	50		V	IR = 5.0 μA
C	Capacitance		3.0	pF	VR = 0, f = 1.0 MHz
trr	Reverse Recovery Time (Note 4)		4.0	ns	IF = IF = 10 mA to 200 mA
			6.0	ns	IF = IF = 200 mA to 400 mA
trr	Reverse Recovery Time (Note 3)		6.0	ns	IF = 10 mA, IR = 1.0 mA

NOTES:

1. The maximum ratings are limiting values above which life or satisfactory performance may be impaired.
2. These are steady-state limits. The factory should be consulted on applications involving pulses or low duty-cycle operations.
3. Recovery to 0.1 mA.
4. Recovery to 10% of IF.
5. For product family characteristic curves, refer to Chapter 4, D4.